IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

IAP5 Rec'd PCT/PTO 27 SEP 2006

MOSELUND ET AL

Atty. Ref.:

2590-169

Serial No.

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Unknown

Group:

National Phase of:

PCT/IB2005/051049

International Filing Date: 29 March 2005

Filed:

Herewith

Examiner:

For:

LIGHT PHASE MODULATOR

September 27, 2006

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

As suggested by 37 C.F.R. 1.97, the undersigned attorney brings to the attention of the Patent and Trademark Office the references listed on the attached form PTO/SB/08a. Copies of the non-U.S. references are enclosed. This is not to be construed as a representation that a search has been made or that no better prior art exists, or that a reference is relevant merely because cited. A copy of the International Search Report, as well as the Written Opinion, are also enclosed.

The Examiner is requested to initial the attached form PTO/SB/08a and to return a copy of the initialed document to the undersigned as an indication that the attached references have been considered and made of record.

Respectfully submitted,

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INFORMATION DISCLOSURE CITATION

ATTY, DUCKET NO.

Unknown 10/594391

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(Use several sheets if necessary)

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Examiner			Date Considered	1			

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.